



Docket No.: 0941-0924P  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Re Patent Application of:  
Min-hung Lee et al.

Application No.: 10/791,816

Confirmation No.: 003667

Filed: March 4, 2004

Art Unit: 2811

For: STRAINED SILICON CARBON ALLOY  
MOSFET STRUCTURE AND FABRICATION  
METHOD THEREOF

Examiner: S. Hu

**FIRST PRELIMINARY AMENDMENT**

MS RCE  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**INTRODUCTORY COMMENTS**

In reply to the Final Office Action dated October 11, 2005, and in view of the Request for Continued Examination being filed concurrently herewith, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

This reply includes:

Amendments to the Claims; and

Remarks.